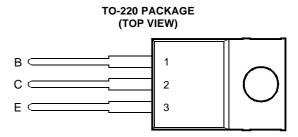
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- Designed for Complementary Use with TIP115, TIP116 and TIP117
- 50 W at 25°C Case Temperature
- 4 A Continuous Collector Current
- Minimum h_{FE} of 500 at 4 V, 2 A



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	TIP110		60		
Collector-base voltage ($I_E = 0$)	TIP111	V _{CBO}	80	V	
	TIP112		100		
	TIP110		60		
Collector-emitter voltage ($I_B = 0$)	TIP111	V _{CEO}	80	V	
	TIP112		100		
Emitter-base voltage			5	V	
Continuous collector current			4	A	
Peak collector current (see Note 1)			6	A	
Continuous base current			50	mA	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			50	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W	
Unclamped inductive load energy (see Note 4)			25	mJ	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds			260	°C	

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$

2. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = 5 mA, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = 20 V.





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electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 30 mA (see Note 5)	I _B = 0	TIP110 TIP111 TIP112	60 80 100			V
I _{CEO}	Collector-emitter cut-off current	$V_{CE} = 30 V$ $V_{CE} = 40 V$ $V_{CE} = 50 V$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$	TIP110 TIP111 TIP112			2 2 2	mA
I _{CBO}	Collector cut-off current	$V_{CB} = 60 V$ $V_{CB} = 80 V$ $V_{CB} = 100 V$	$I_{E} = 0$ $I_{E} = 0$ $I_{E} = 0$	TIP110 TIP111 TIP112			1 1 1	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0				2	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_{\rm C} = 1 \text{ A}$ $I_{\rm C} = 2 \text{ A}$	(see Notes 5 and 6)	1000 500			
V _{CE(sat)}	Collector-emitter saturation voltage	I _B = 8 mA	I _C = 2 A	(see Notes 5 and 6)			2.5	V
V _{BE}	Base-emitter voltage	V _{CE} = 4 V	I _C = 2 A	(see Notes 5 and 6)			2.8	V
V _{EC}	Parallel diode forward voltage	I _E = 4 A	I _B = 0	(see Notes 5 and 6)			3.5	V

NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle \leq 2%.

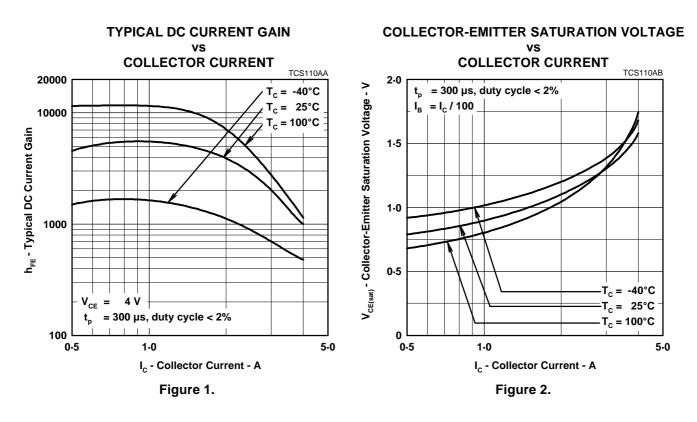
6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = 2 A	I _{B(on)} = 8 mA	I _{B(off)} = -8 mA		2.6		μs
t _{off}	Turn-off time	$V_{BE(off)} = -5 V$	$R_L = 15 \Omega$	t_p = 20 µs, dc \leq 2%		4.5		μs

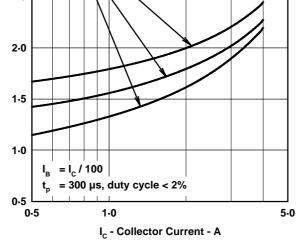
[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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TYPICAL CHARACTERISTICS

BASE-EMITTER SATURATION VOLTAGE vs **COLLECTOR CURRENT** TCS110AC 3.0 -40°C T_c = $T_c = 25^{\circ}C$ T_c = 100°C 2.5 2.0 1.5





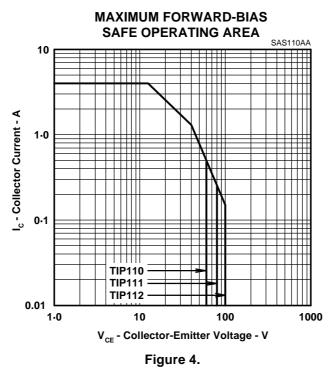


PRODUCT INFORMATION

V_{BE(sat)} - Base-Emitter Saturation Voltage - V

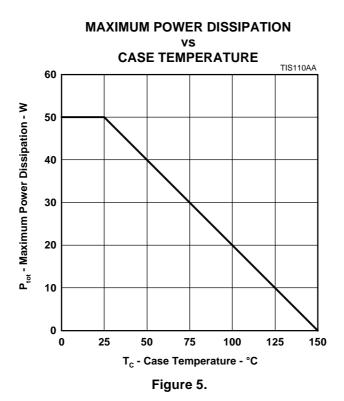
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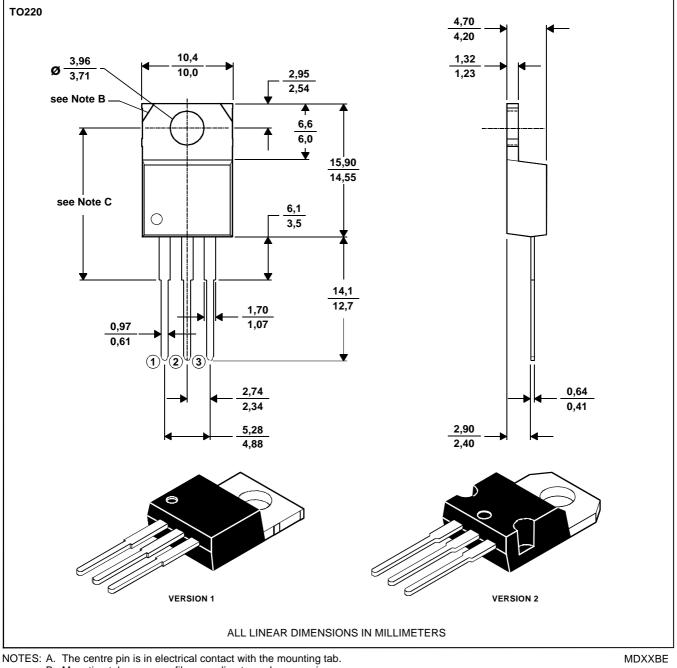
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version.

Version 1, 18.0 mm. Version 2, 17.6 mm.

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